RICOH

R3119N SERIES

36V INPUT VOLTAGE DETECTOR

NO.EA-187-111104

OUTLINE

R3119N Series are CMOS-based 36V input (absolute maximum ratings: 50V) voltage detector with high detector threshold accuracy and ultra-low supply current. Each of those ICs consists of a voltage reference unit, a comparator, resistors for detector threshold setting, an output driver and a hysteresis circuit.

There are two types: R3119NxxxA has the C_D pin for setting the output delay time. R3119NxxxE has the SENSE pin.

The supply current of IC is only 3.3µA. The detector threshold is fixed in the IC and can be set with a step of 0.1V in the range of 2.3V to 12V. Detector threshold accuracy is 1.5%. The output type is Nch Open drain type. Since the package for these ICs is small SOT-23-5, high density mounting of the ICs on board is possible.

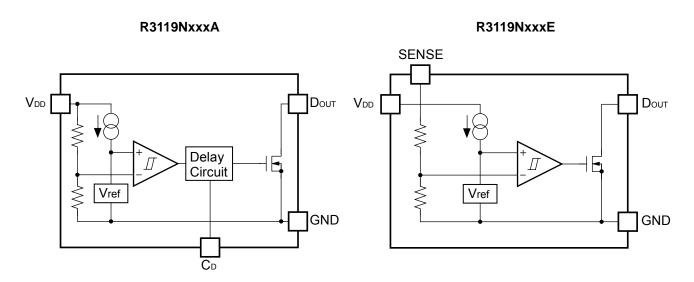
FEATURES

Supply Current	Τyp. 3.3μA
Operating Voltage Range	1.2V to 36.0V (C _D pin type: R3119NxxxA)
	2.1V to 6.0V (SENSE pin type: R3119NxxxE)
Operating Temperature Range	40°C to 105°C
Detector Threshold Range	2.3V to 12.0V (0.1V steps)
	(For other voltages, please refer to MARK INFORMATIONS.)
Detector Threshold Accuracy	±1.5% (Topt=25°C)
Temperature-Drift Coefficient of Detector Threshold	Typ. ±100ppm/°C
• Output Delay Time (Power ON Reset Delay Time)	Typ. 85ms (C□=0.01μF, C□ pin type)
Output Delay Time Accuracy	50% to 80% (C _D pin type: R3119NxxxA)
Output Type	Nch Open Drain
Package	SOT-23-5

APPLICATIONS

- · CPU and Logic Circuit Reset
- · Battery Checker
- · Battery Back-up Circuit
- Power Failure Detector for Digital home appliances

BLOCK DIAGRAMS



SELECTION GUIDE

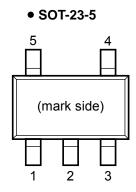
The package type, the detector threshold and the version for the ICs can be selected at the users' request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
R3119Nxxx*-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes

xxx: The detector threshold can be designated in the range from 2.3V(023) to 12.0V(120) in 0.1V steps. (For other voltages, please refer to MARK INFORMATIONS.)

- * : Designation of Version
 - (A) with C_D pin type
 - (E) with SENSE pin type

PIN CONFIGURATIONS



PIN DESCRIPTIONS

• SOT-23-5

Pin No.	Symbol		Description					
1	V_{DD}	Input Pin						
2	GND*	Ground Pin						
3	GND*	Ground Pin	round Pin					
4	D оит	Output Pin ("	Output Pin ("L" at detection)					
5	С	R3119NxxxA	Connecting pin with external capacitor for setting delay time					
3	SENSE R3119NxxxE Voltage Detector Voltage Sense Pin							

^{*)} No. 2 and No.3 pins must be wired to the GND plane when it is mounted on board.

ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Item		Unit	
V _{DD}	Supply Voltage	R3119NxxxA	-0.3 to 50.0	V	
טט ע	Supply Vollage	R3119NxxxE	-0.3 to 7.0	v	
Vout	Output Voltage (Dout Pin)		-0.3 to 7.0	V	
Vcd	Output Voltage (C _D Pin) R3119NxxxA		-0.3 to 7.0	V	
Vsense	Input Voltage (SENSE Pin)	R3119NxxxE	-0.3 to 50.0		
louт	Output Current (Dout Pin)	Output Current (Dout Pin)			
PD	Power Dissipation (SOT-23-5)	Power Dissipation (SOT-23-5)*		mW	
Topt	Operating Temperature Range		-40 to 105	°C	
Tstg	Storage Temperature Range		-55 to 125	°C	

^{*)} For Power Dissipation, please refer to PACKAGE INFORMATION.

ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

ELECTRICAL CHARACTERISTICS

• R3119NxxxA (C_D pin type)

The sp	ecification in	 is checked	and o	guaranteed	by desig	n engineering	at -40°C	≤ Topt	≤ 105°C.

Topt=25°C

Symbol	Item	C	ondition	าร	Min.	Тур.	Max.	Unit
-V _{DET}	Detector Threshold	V _{DD} pin	Topt=25°C		×0.985		×1.015	· V
- V DET	Detector Tilleshold	טט אווו	-40°C	$-40^{\circ}C \leq Topt \leq 105^{\circ}C$			×1.020	V
V _{HYS}	Detector Threshold Hysteresis				3.5	5	6.5	%
Iss	Supply Current	V _{DD} = -V _{DET} -0.1	V			3.3	5.6	μА
133	Оприу Оптент	V _{DD} = -V _{DET} +1.0	V			3.3	5.5	μΑ
V _{DDH}	Maximum Operating Voltage						36	V
V _{DDL}	Minimum Operating	Topt=25°C					1.2	V
V DDL	Voltage [*]	-40°C ≤ Topt ≤	$-40^{\circ}C \le Topt \le 105^{\circ}C$				1.25	'
	Output Current	V _{DD} =1.5V, V _{DS} =0.05V			230			μА
		2.3V ≤ -V _{DET} <	2.6V	V _{DD} =2.2V V _{DS} =0.5V	2.8			
Іоит	(Driver Output Pin)	2.6V ≤ -V _{DET} <	3.0V	V _{DD} =2.5V V _{DS} =0.5V	3.3			mA
				V _{DD} =2.9V V _{DS} =0.5V	3.5			
ILEAK	Nch Driver Leakage Current	V _{DD} =36V, V _{DS} =6.0V					0.2	μА
Δ -V _{DET} / Δ Topt	Detector Threshold Temperature Coefficient	$-40^{\circ}C \le Topt \le 105^{\circ}C$				±100		ppm /°C
tdelay	Detector Output Delay Time	$V_{DD}=1.5V \rightarrow -V_{DD}=0.01 \mu F$	/ _{DET} +2.0\	/	45	85	150	ms

All of unit are tested and specified under load conditions such that $T_j \approx T_{opt} = 25^{\circ}C$ except for Detector Threshold Temperature Coefficient.

*) This value is the minimum input voltage when the output voltage is 0.1V or less at detection. (The pull-up resistance; $100k\Omega$, the pull-up voltage; 5.0V)

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

R3119N

• R3119NxxxE (SENSE pin type)

The specification in ____ is checked and guaranteed by design engineering at $-40^{\circ}\text{C} \le \text{Topt} \le 105^{\circ}\text{C}$.

Topt=25°C

Symbol	Item	Conditions			Min.	Тур.	Max.	Unit	
V _{DD}	Operating Voltage				2.1*		6	٧	
-V _{DET}	-VDET Detector Threshold		SENSE pin Topt=25°C		×0.985		×1.015	V	
-VDEI	Detector Trireshold	V _{DD} =6V	-40°C :	≤ Topt ≤ 105°C	×0.970		×1.020	V	
V _{HYS}	Detector Threshold Hysteresis	V _{DD} =6V			3.5	5	6.5	%	
lss	Supply Current	VDD=6V, VSENSE	= -VDET-	0.1V		3.3	5.5		
155	Зирріу Сипепі	V _{DD} =6V, V _{SENSE} = -V _{DET} +1.0V				3.3	5.5	μΑ	
RSENSE	Sense Resistor				4.5		120	ΜΩ	
Output Current		Vsense < -Vdet		V _{DD} =2.1V V _{DS} =0.05V	420			μА	
1001	(Driver Output Pin)	Vsense < -Vdet		V _{DD} =2.2V V _{DS} =0.5V	2.8			mA	
ILEAK	Nch Driver Leakage Current	VDD=6V, VSENSE=36V, VDS=6.0V					0.2	μΑ	
Δ -V _{DET} / Δ Topt	Detector Threshold Temperature Coefficient	$-40^{\circ}C \le Topt \le 105^{\circ}C$				±100		ppm /°C	
t PLH	Output Delay Time	$V_{DD}=6V$ $V_{SENSE}=1.5V \rightarrow -V_{DET}+2.0V$				15		μS	
Vsense	Input Voltage (SENSE Pin)				0		36	V	

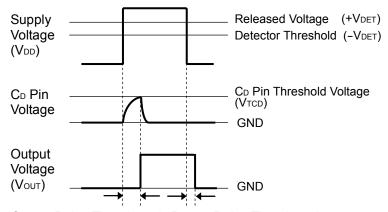
All of unit are tested and specified under load conditions such that Tj≈Topt=25°C except for Detector Threshold Temperature Coefficient and Output Delay Time.

*) Minimum operating voltage of "SENSE pin type" is minimum supply voltage to obtain correct detection voltage.

RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

TIMING CHART



Output Delay Time (tdelay) Detect Delay Time (treset)

When the supply voltage, which is higher than released voltage, is forced to V_{DD} pin, charge to an external capacitor starts, then C_{D} pin voltage increases. Until the C_{D} pin voltage reaches to C_{D} pin threshold voltage, output voltage maintains "L". When the C_{D} pin voltage becomes higher than C_{D} pin threshold voltage, output voltage is reversed from "L" to "H". Where the time interval between the rising edge of supply voltage and output voltage reverse point means output delay time.

When the output voltage reverses from "L" to "H", the external capacitor starts to discharge. Therefore, when lower voltage than the detector threshold voltage is forced to V_{DD} pin, the output voltage reverses from "H" to "L" thus the detect delay time is constant not being affected by the external capacitor.

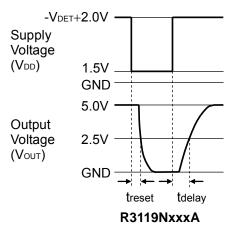
Output Delay Time

Output Delay Time (tdelay) can be calculated with the next formula using the external capacitor: tdelay (s) = $8.5 \times 10^6 \times C_D(F)$

DEFINITION OF OUTPUT DELAY TIME

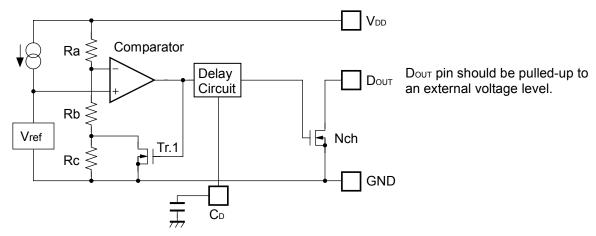
Output Delay Time (tdelay) is defined as follows:

Under the condition of the output pin (DouT) is pulled up through a resistor of $100k\Omega$ to 5V, the time interval between the rising edge of VDD pulse from 1.5V to (-VDET)+2.0V pulse voltage is supplied, the becoming of the output voltage to 2.5V.

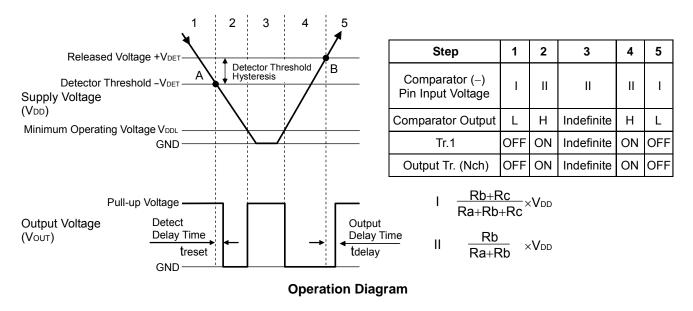


OPERATION

Operation of R3119NxxxA (C_D pin type)



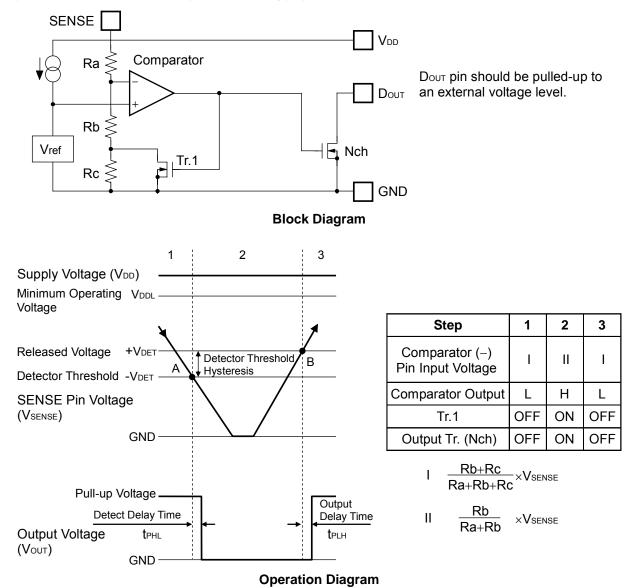
Block Diagram of External Capacitor Connection



Explanation of operation

- Step 1. The output voltage is equal to the pull-up voltage.
- Step 2. At Point "A", Vref ≥ Vdd×(Rb+Rc)/(Ra+Rb+Rc) is true, as a result, the output of comparator is reversed from "L" to "H", therefore the output voltage becomes the GND level. The voltage level of Point A means a detector threshold voltage (-Vdet).
- Step 3. When the supply voltage is lower than the minimum operating voltage, the operation of the output transistor becomes indefinite. The output voltage is equal to the pull-up voltage.
- Step 4. The output voltage is equal to the GND level.
- Step 5. At Point "B", Vref ≤ VDD×Rb/(Ra+Rb) is true, as a result, the output of comparator is reversed from "H" to "L", then the output voltage is equal to the pull-up voltage. The voltage level of Point B means a released voltage (+VDET).
- *) The difference between a released voltage and a detector threshold voltage is a detector threshold hysteresis.

Operation of R3119NxxxE (SENSE pin type)



Explanation of operation

- Step 1. SENSE pin voltage is larger than detector threshold; the output voltage is equal to the pull-up voltage.
- Step 2. At Point "A", Vref ≥ Vsense×(Rb+Rc)/(Ra+Rb+Rc) is true, as a result, the output of comparator is reversed from "L" to "H", therefore the output voltage becomes the GND level. The voltage level of Point A means a detector threshold voltage (-VDET). (When the supply voltage is higher than the minimum operating voltage, the output voltage is equal to the GND level.)
- Step 3. At Point "B", Vref ≤ Vsense×Rb/(Ra+Rb) is true, as a result, the output of comparator is reversed from "H" to "L", then the output voltage is equal to the pull-up voltage. The voltage level of Point B means a released voltage (+VDET).
- *) The difference between a released voltage and a detector threshold voltage is a detector threshold hysteresis.

Power supply injection order

The R3119NxxxE Series supervise the voltage of the SENSE pin. V_{DD} pin and SENSE pin can be used at the same voltage level. Likewise, V_{DD} pin and SENSE pin can be used at the different voltage level. If the V_{DD} pin and SENSE pin are used at different voltage level, regarding the start-up sequence, force the voltage level to V_{DD} pin prior to the SENSE pin.

If the SENSE pin voltage is equal or more than the released voltage ($+V_{DET}$), D_{OUT} pin becomes "H"(Fig.1). Besides, a voltage beyond V_{DD} pin is also acceptable to SENSE pin.

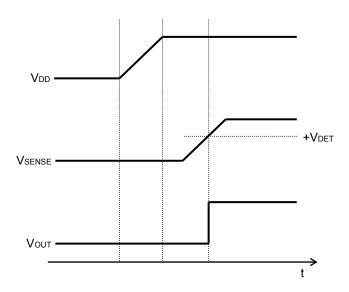
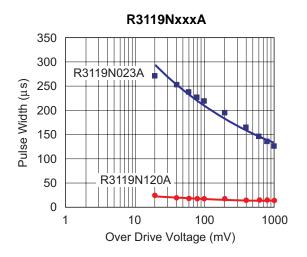
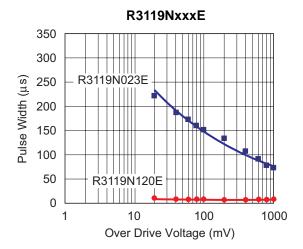


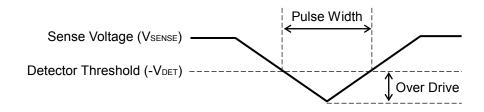
Fig.1 Turn on sequence

Detector Operation vs. glitch input voltage to the VDD pin or SENSE pin

When the R3119N is at released, if the pulse voltage which the detector threshold or lower voltage, the graph below means that the relation between pulse width and the amplitude of the swing to keep the released state for the R3119N.





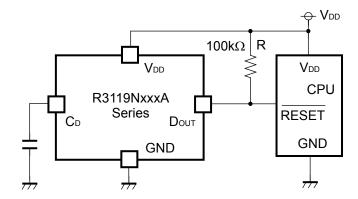


VSENSE Input Waveform

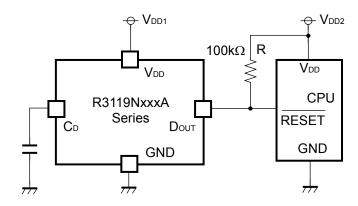
This graph shows the maximum pulse conditions to keep the released voltage. If the pulse with larger amplitude or wider width than the graph above, is input to the V_{DD} pin (R3119NxxxA) or to the SENSE pin (R3119NxxxE), the reset signal may be output.

TYPICAL APPLICATION

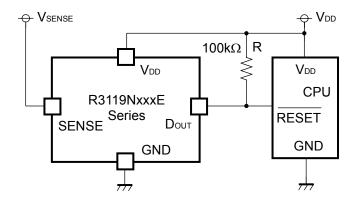
- R3119NxxxA (C_D pin type)
- (1) Input Voltage to R3119NxxxA is equal to Input Voltage to CPU



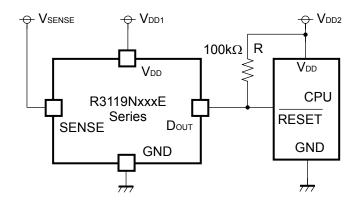
(2) Input Voltage to R3119NxxxA is unequal to Input Voltage to CPU



- R3119NxxxE (SENSE pin type)
- (1) Input Voltage to R3119NxxxE is equal to Input Voltage to CPU

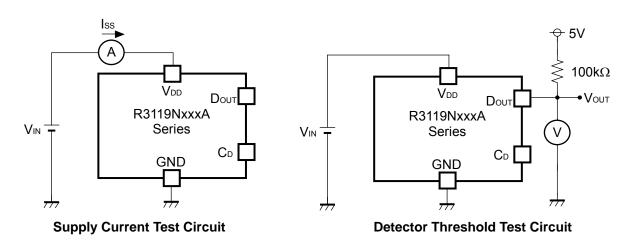


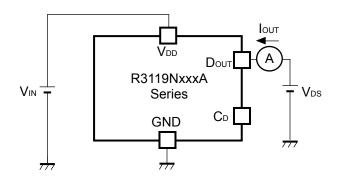
(2) Input Voltage to R3119NxxxE is unequal to Input Voltage to CPU



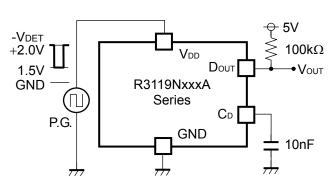
TEST CIRCUITS

• R3119NxxxA (Cp pin type)



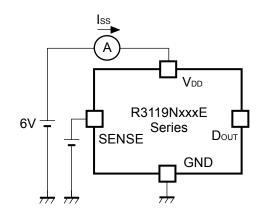


Nch Driver Output Current Test Circuit

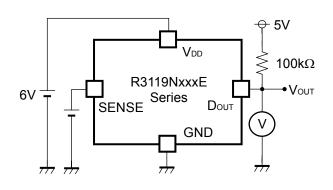


Output Delay Time Test Circuit

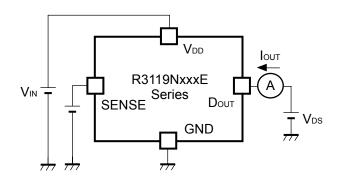
• R3119NxxxE (SENSE pin type)



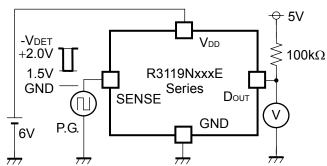
Supply Current Test Circuit



Detector Threshold Test Circuit



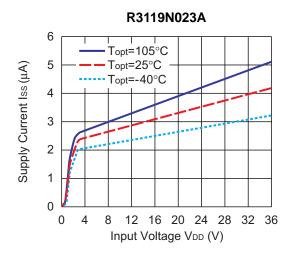
Nch Driver Output Current Test Circuit

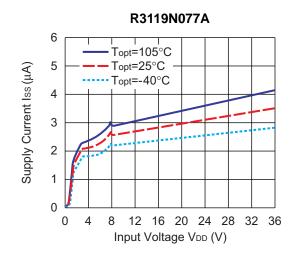


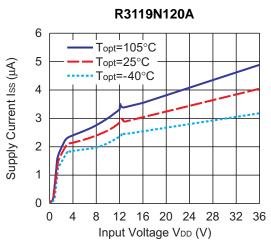
Output Delay Time Test Circuit

TYPICAL CHARACTERISTICS

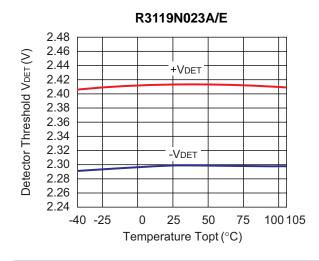
1) Supply Current vs. Input Voltage

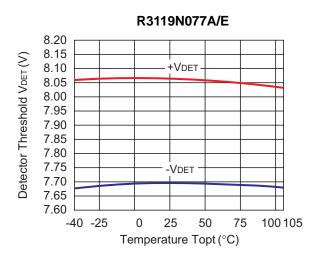




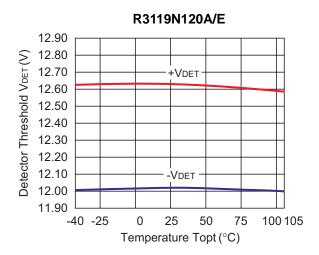


2) Detector Threshold vs. Temperature

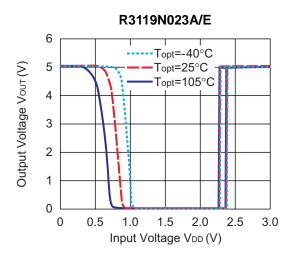


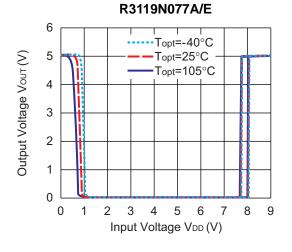


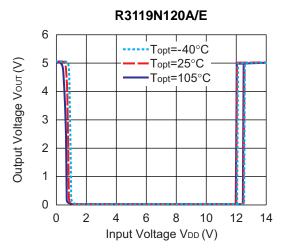
R3119N



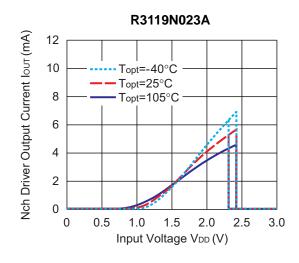
3) Output Voltage vs. Input Voltage

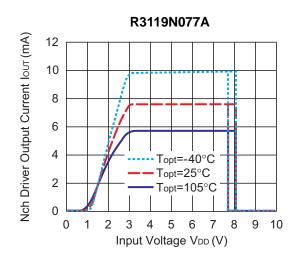


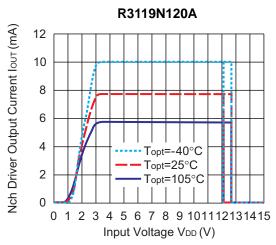




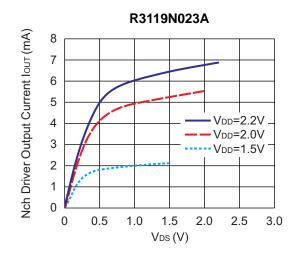
4) Nch Driver Output Current vs. Input Voltage

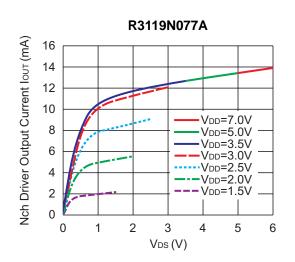




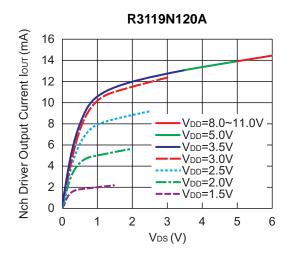


5) Nch Driver Output Current vs. VDS

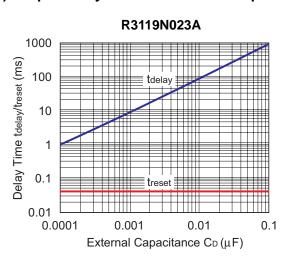


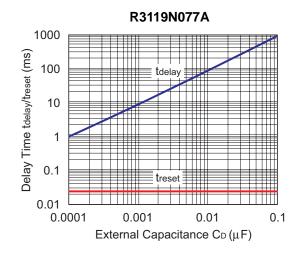


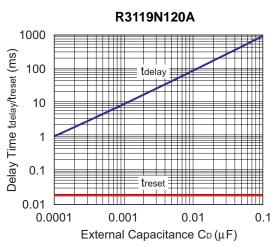
R3119N



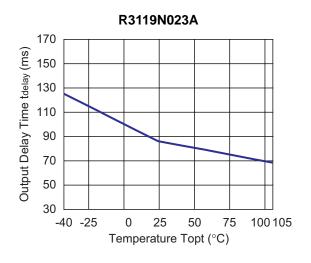
6) Output Delay Time vs. External Capacitance (Topt=25°C)

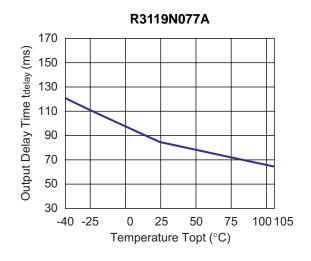


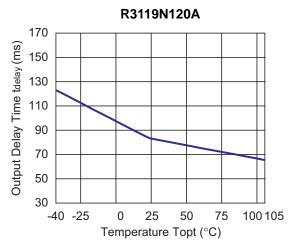




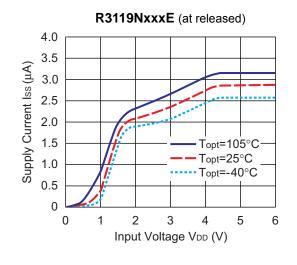
7) Output Delay Time vs. Temperature (CD=0.01μF)

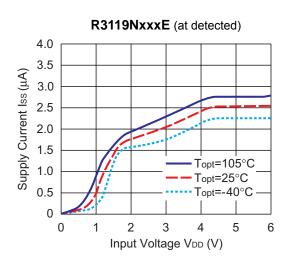




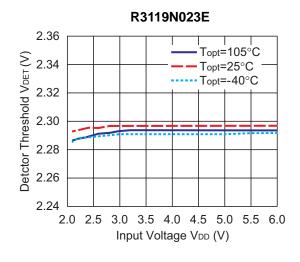


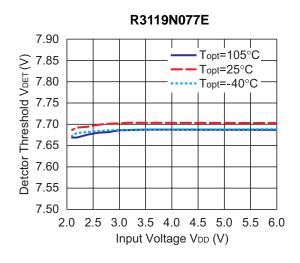
8) Supply Current vs. Input Voltage

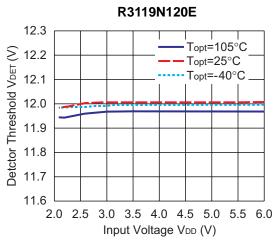




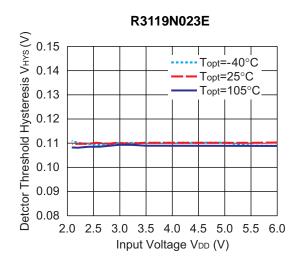
9) Detector Threshold vs. Input Voltage

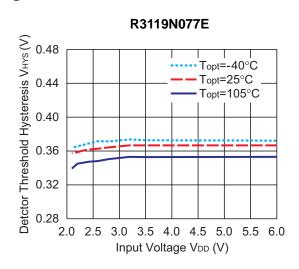


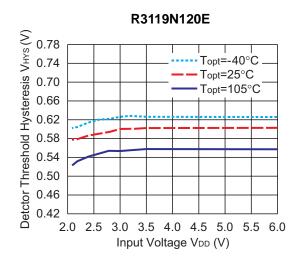




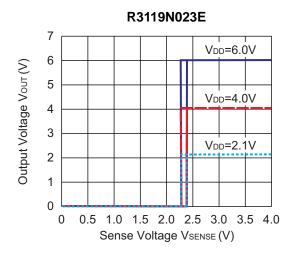
10) Detector Threshold Hysteresis vs. Input Voltage

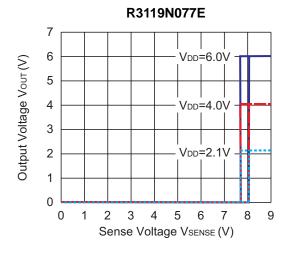


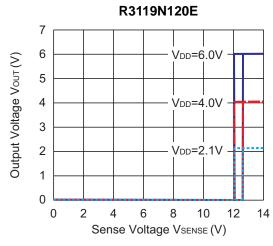




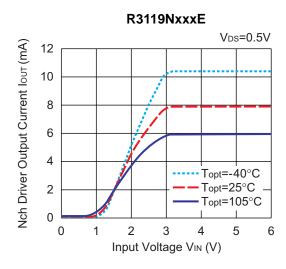
11) Output Voltage vs. SENSE pin Input Voltage (Topt=25°C) (Dout pull up to VDD with 100kΩ)



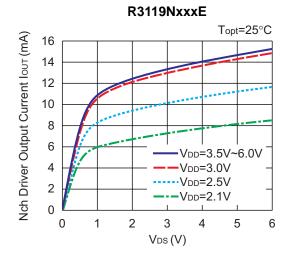




12) Nch Driver Output Current vs. Input Voltage



13) Nch Driver Output Current vs. VDS

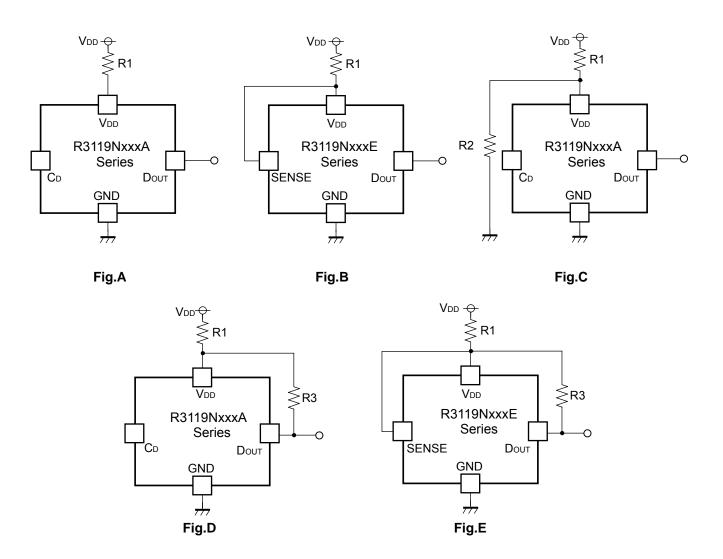


TECHNICAL NOTES

When R3119NxxxA/E is used in Fig.A, Fig.B, if the value of R1 is set excessively large, the dropdown voltage caused by the consumption current of IC itself, may vary the detector threshold and the release voltage. Also, if the value of R1 is set excessively large, there may be delay in start-up and may cause oscillation generated by cross conduction current.

When R3119NxxxA is used in Fig.C, if the value of R1 is set excessively large, the dropdown voltage caused by the consumption current of IC itself, may vary the detector threshold and the released voltage. Also, if the value of R1 and R2 is set excessively large, there may be delay in start-up and may cause oscillation generated by cross conduction current.

When R3119NxxxA/E is used in Fig.D, Fig.E, if the value of R1 is set excessively large, the dropdown voltage caused by the consumption current of IC itself may vary the detector threshold and the release voltage. Also, if the value of R1 is set excessively large, there may be delay in start-up and may cause oscillation generated by cross conduction current. Furthermore, if the value of R1 is set large and the value of R3 is set small, released voltage level may shift and the minimum operating voltage may differ. If the value of R3 is set excessively small from R1, release may not occur and may cause oscillation.





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